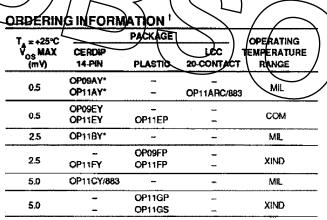


Quad Matched 741-Type Operational Amplifiers

OP-09/0P-11

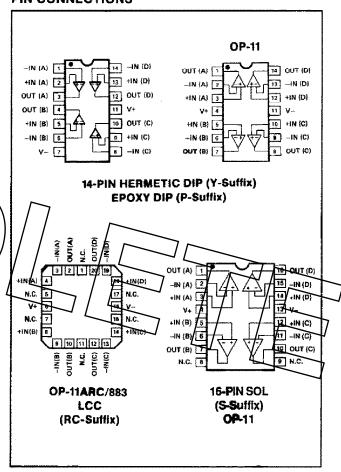
FEATURES

- Guaranteed Matched Vos 750 µV Max
- RC/RM4136 Direct Replacement (OP-09)
- LM148/LM348 Direct Replacement (OP-11)
- Low Noise
- Silicon-Nitride Passivation
- Internal Frequency Compensation
- Low Crossover Distortion
- Continuous Short-Circuit Protection
- . Low input Blas Current
- Available in Die Form

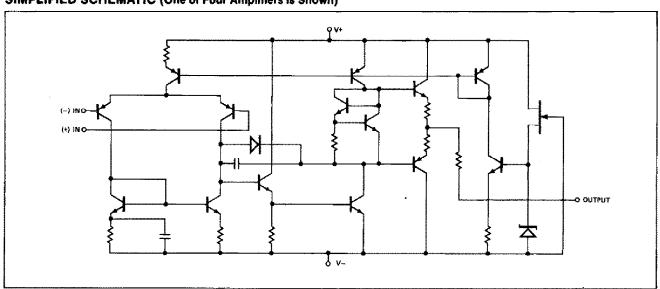


- For devices processed in total compliance to MIL-STD-883, add /883 after part number. Consult factory for 883 data sheet.
- Burn-in is available on commercial and industrial temperature range parts in CerDIP, plastic DIP, and TO-can packages.

PIN CONNECTIONS



SIMPLIFIED SCHEMATIC (One of Four Amplifiers is Shown)



OP-09/OP-11

GENERAL DESCRIPTION

The OP-09 and OP-11 provide four matched 741-type operational amplifiers in a single 14-pin DIP package. The OP-11 is pin compatible with the LM148, LM348, RM4156, and HA4741 amplifiers. The OP-09 is pin compatible with the RM4136 and RC4136. The amplifiers are matched for common-mode rejection ratio and offset voltage which is very important in designing instrumentation amplifiers. In addition, the amplifier is designed to have equal positive-going and negative-going slew rates. This is an important consideration for good audio system performance.

Each of the four amplifiers has the proven OP-02 advantages of low noise, low drift, and excellent long-term stability. Precision Monolithics' exclusive Silicon-Nitride "Triple Passivation" process reduces "popcorn noise", provides high reliability, and assures long-term stability of parameters.

The OP-09 and OP-11 are ideal for use in designs requiring minimum space and cost white maintaining OP-02-type performance.

OP-09's and OP-11's with processing per the requirements of MIL-STD-883 are available. For dual 741-type versions, see the OP-04/14 data sheet.

ABSOLUTE	MAXIMUM	RATING	S (Note 1)
-----------------	---------	--------	------------

Supply Voltage	\ ±22V
OP-09GR and OP-11GR (Only)	±18V
Differential Input Voltage	±30 V
Input Voltage	Supply Voltage
Output Short-Circuit Duration	Continuous
	(One Amplifier Only)

Storage Temperature Ran	ge		
RC, Y-Package		65°C	to +150°C
P-Package			
Lead Temperature Range			
Junction Temperature (T _i)			
Operating Temperature Ra			
OP-09A, OP-09B	•	–55°C	to +125°C
OP-09E			
OP-09F			
OP-11A, OP-11B,			
OP-11C, OP-11ARC	**************	–55°C	to +125°C
OP-11E	***************	0°(C to +70°C
OP-11F, OP-11G			
PACKAGE TYPE	⊖ _{jA} (Note 2)	Θ _{jc}	UNITS
14-Pin Hermetic DIP (Y)	108	16	°C/W
14-Pin Plastic DIP (P)	83	39	*C/W
20-Contact LCC (RC)	98	33	°C/W
16-Pin SOL (S)	98	30	°C/W

NOTES:

Absolute maximum ratings apply to both DICE and packaged parts, unless otherwise noted.

P. O is specified for worst case mounting conditions, i.e., O is specified for device in specket for CerDIP, P-DIP, and LCC packages; O is specified for device solfiered to printed firetit board for SOL package.



MATCHING CHARACTERISTICS at $V_S=\pm 15V$, $T_A=\pm 25^{\circ}$ C, $R_S \leq 100\Omega$, unless otherwise noted.

PARAMETER			OP-0 OP-1		P-09F P-11F				
	SYMBOL	CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
Input Offset Voltage Match	ΔV _{OS}			0.5	0.75		0.8	2.0	mV
Common-Mode Rejection		V _{CM} = ±12V		1	20		1	20	μV/V
Ratio Match	∆CMRR	V _{CM} = ± 12V	94	120		94	120		dB

MATCHING CHARACTERISTICS at $V_S = \pm 15V$, $-55^{\circ}C \le T_A \le +125^{\circ}C$ for OP-09A, OP-09B, OP-11A, OP-11B, $0^{\circ}C \le T_A \le +70^{\circ}C$ for OP-09E, OP-11E and $-40^{\circ}C \le T_A \le +85^{\circ}C$ for OP-09F, OP-11F, $R_S \le 100\Omega$, unless otherwise noted.

				9A, OI		OP-0 OP-1			
PARAMETER	SYMBOL	CONDITIONS	MIN	TÝP	MAX	MIN	TYP	MAX	UNITS
Input Offset Voltage Match	ΔV _{OS}		_	0.6	1.0		1.0	2.5	mV
Common-Mode Rejection		V _{CM} = ±12V		3.2	20	_	3.2	20	μV/V
Ratio Match	ACMRR	$V_{CM} = \pm 12V$	94	110		94	110_		dB

OP-09/OP-11

ELECTRICAL CHARACTERISTICS (Each Amplifier) at $V_8 = \pm\,15V$ $T_A = 25^{\circ}$ C, unless otherwise noted.

PARAMETER		•	-	OP-09A/E OP-11A/E			OP-09B/F OP-11B/F			· OP-11C/G		
	SYMBOL	CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	/G MAX	UNITS
Input Offset Voltage	Vos	R _S ≤ 10kΩ		0.3	0.5		0.6	2.5		1.2	5.0	m\
input Offset Current	los			5.5	20		25	50		75	200	n/
Input Bias Current	l _B		-	180	300		300	500	_	300	500	n/
Input Resistance Differential Mode	R _{IN}	(Note 3)	0.17	0.29		0.1	0.17		0,1	0.17	_	М
Input Voltage Range	IVR		±12	± 13	_	±12	± 13	_	±12	±13		Ī
Gommon-Mode Rejection Ratio	CMRR	$V_{CM} = \pm 12V$, $R_S \le 10k\Omega$	100	120	-	100	120	*****	70	100	_	d£
Power Supply Rejection Ratio	PSRR	$V_S = \pm 5 \text{ to } \pm 15 \text{V},$ $R_S \le 10 \text{k}\Omega$	_	4	32	. -	4	32	_	10	100	√∨ب
Output Voltage Swing	-Va_	A _L ≥ 2kΩ	±11	± 13		±11	± 13		±11	±13	_	1
Large-Signal Voltage Gain	Avo	R ₁ ≤ 2kΩ, Vo = ±10V	100	650	wnenw	100	650		50	500	_	V/m\
Power Consumption (Note 1)	<u>~</u>	V ₀ €0V	_	105	180	_	123	180		210	340	m∀
Imput Noise Voltage	e _{no-r})	0.1Hz 10-10Hz	<u> </u>	70.7	$f \cap$	_	0.7	*****		0.7		μ٧ _{p-}
Input Noise Voltage Density	e _n	f _O = 10Hz f _O = 100Hz f _O = 1000Hz	(=	18 14 12	<u> -</u>		18 14 12/]/=	18 14 12		nV/√Hz
Input Noise Current	i _{np-p}	0.1Hz to 10Hz		/17	1-/		17			17	7-1	_pA _₽
Input Noise Current Density	In	f _O = 10Hz f _O = 100Hz f _O = 1000Hz	~~~	1.8 1.5 1.2			1/8 1.5 1.2		7	1.8 1.5 1.2	7	₽A√Hz
Channel Separation	CS	mort 2000 - Control of the Control o	100	130	_	100	130	=	/	130	7-7	dE
Siew Rate (Note 2)	SR		0.7	1.0		0.7	1.0	*****	لري	1.0	<i>T_t</i>	V/μ
Large-Signal Bandwidth (Note 2)		V _O = 20V _{P-P}	11	16	****	11	16	_	11	16		
Closed-Loop Bandwidth (Note 4)	8W	A _{VCL} = ÷1.0	2.4	3.0	_	2.4	3,0	-	2.4	3.0	_	мн
Risetime (Note 2)	t _r	A _V = +1, V _{IN} = 50mV		110	145		110	145	_	110	145	n
Overshoot (Note 2)	os			15	25	Partie	15	25		15	25	ų

NOTES:

- 1. Total dissipation for all four amplifiers in package.
- 2. Sample tested.
- 3. Guaranteed by input bias current.
- 4. Guaranteed by risetime.

 $\label{eq:continuous} \begin{array}{l} \textbf{OP-09/0P-11} \\ \textbf{ELECTRICAL CHARACTERISTICS (Each Amplifier) at V}_S = \pm\,15\text{V}, -55^{\circ}\text{C} \leq T_A \leq +\,125^{\circ}\text{C}, \text{ unless otherwise noted.} \end{array}$

)P-09/)P-11/		_)P-09E)P-11B		()P-110	_	
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
Input Offset Voltage	Vos	R _S ≤ 10kΩ		0.4	1.0	_	1.0	3.5	_	1.5	6.0	mV
Average Input Offset Voltage Drift (Note 3)	TCV _{os}	R _S ≤10kΩ	wear	2.0	10	******	4.0	15	*****	4.0	••••	μV/°C
input Offset Current	los			20	40		40	80		250	300	nA
Average Input Offset Current Drift (Note 3)	TCIOS		-	0.1	0.3	_	0.3	0.6	-	0.3	0.6	nA/°C
Input Bias Current	18		-	200	375	_	400	650	_	400	800	nA
Input Voltage Range	IVR		± 12	±13		±12	± 13	*****	±12	±13		v
Commen-Mode Rejection Ratio	CMRR	V _{CM} = ±12V, R _S ≤10kΩ	100	120		100	120	_	70	100	_	dB
Power Supply Rejection Ratio	SRR	$V_S = \pm 5$ to $\pm 15V$, $R_S \ge 10k\Omega$	_	4	32	_	4	32	-	10	100	μV/V
arge-Signal Voltage Gain	Avo	$R_L \ge 2k\Pi_1/V_0 = \pm \frac{10V}{10}$	50	250		50	250		25	100		V/mV
Sutput Voltage Swing	v _b	R _L ≥ 2kn	±11	±13	/-	±11	±13		±11	± 13		v
		va= 0	17	115	200	17_	115	,200	_	250	400	mW
Power Consumption (Note 1) ELECTRICAL CH or OP-09F, OP11F	IARACT , OP-11G	ERISTICS (Each Am	plifier) a		}-}-/	C≰T _A ≤+	-70°C1	or OP-09	DE, OP-1	4E -	10°C≤	### +85°C
(Note 1)	IARACT	ERISTICS (Each Am	ed.	.V _e √. .P-09E	1	/	17-09F			7	/	# _A ≤+85°C
(Note 1)	IARACT	ERISTICS (Each Am	ed.	ار الحولان	1	/	/)P-/10		
(Note 1) ELECTRICAL CHOR OP-09F, OP11F	IARACT , OP-11G	ERISTICS (Each Am	ed.	P-09E	15V, 0°C		17-09F 17-1/1F)P-110 T/P	/	UNITS
ELECTRICAL CHOR OP-09F, OP11F PARAMETER Input Offset Voltage Average Input Offset	IARACT , OP-11G	ERISTICS (Each Am	ed.	P-09E)P-11E TYP	15V, 0°(MIN	17-09F 17-1/1F 17P	MAX)P-/10	MAX	
ELECTRICAL CHOR OP-09F, OP11F PARAMETER Input Offset Voltage Average Input Offset Voltage Drift	SYMBOL Vos	ERISTICS (Each Am a, unless otherwise not conditions R _S ≤ 10kΩ	ed.	DP-09E DP-11E TYP	15V, 0°0	MIN	77-09F 77-1/1F TYP 0.8	MAX 3.0		0P-110 T/YP 1.5	6.0	UNITS mV mV/°C
ELECTRICAL CHOR OP-09F, OP11F PARAMETER Input Offset Voltage Average Input Offset	ARACT , OP-11G SYMBOL Vos	ERISTICS (Each Am a, unless otherwise not conditions R _S ≤ 10kΩ	ed.	DP-09E DP-11E TYP 0.4	MAX 0.8	MIN	77-09F 27-1/1F TYP 0.8 4.0	3.0 15		DP-110 TVP	MAX	UNITS
ELECTRICAL CHOR OP-09F, OP11F PARAMETER Input Offset Voltage Average Input Offset Voltage Drift Input Offset Current Average Input Offset	SYMBOL Vos TCVos	ERISTICS (Each Am a, unless otherwise not conditions R _S ≤ 10kΩ	ed.	DP-09E DP-11E TYP 0.4 2.0	MAX 0.8	MIN	0.8 4.0	3.0 15 60	MIN	DP-110 TVP 1.5 4.0 250	6.0 —	UNITS mV
ELECTRICAL CHOR OP-09F, OP11F PARAMETER Input Offset Voltage Average Input Offset Voltage Drift Input Offset Current Average Input Offset Current Drift (Note 3)	SYMBOL Vos TCVos	ERISTICS (Each Am a, unless otherwise not conditions R _S ≤ 10kΩ	ed. COMIN	DP-09E DP-11E TYP 0.4 2.0 14	MAX 0.8 10 30	MIN	77-09F DP-1/1F TYP 0.8 4.0 40 0.3	3.0 15 60 0.6	MIN	DP-110 T/YP 1.5/ 4.0 250 0.3	MAX 6.0 — 300 0.6	UNITS mV nA/°C nA/°C
ELECTRICAL CHOR OP-09F, OP11F PARAMETER Input Offset Voltage Average Input Offset Voltage Drift Input Offset Current Average Input Offset Current Drift (Note 3) Input Bias Current	SYMBOL VOS TCVOS TCIOS	ERISTICS (Each Am a, unless otherwise not conditions R _S ≤ 10kΩ	ed.	DP-09E DP-11E TYP 0.4 2.0 14 0.1	MAX 0.8 10 30 0.3 350	MIN	0.8 4.0 0.3 400	3.0 15 60 0.6 550	Min -	DP-110 TVP 1.5 4.0 250 0.3 400	MAX 6.0 — 300 0.6 800	UMITS mV nA/°C nA
ELECTRICAL Chor OP-09F, OP11F PARAMETER Input Offset Voltage Average Input Offset Voltage Drift Input Offset Current Average Input Offset Current Drift (Note 3) Input Bias Current Input Voltage Range Common-Mode	SYMBOL Vos TCVos TCIos IB IVR	ERISTICS (Each Amai, unless otherwise not conditions $R_S \le 10 k\Omega$	ed. C MIN	DP-09E DP-11E TYP 0.4 2.0 14 0.1 200 ± 13	MAX 0.8 10 30 0.3 360	MIN	0.8 4.0 4.0 4.0 4.0 4.0 4.13	3.0 15 60 0.6 550		DP-110 TVP 1.5 4.0 250 0.3 400 ±13	MAX 6.0 — 300 0.6 800	UNITS mV nA/°C nA nA/°C
ELECTRICAL Chor OP-09F, OP11F PARAMETER Input Offset Voltage Average Input Offset Voltage Drift Input Offset Current Average Input Offset Current Drift (Note 3) Input Voltage Range Common-Mode Rejection Ratio	SYMBOL Vos TCVos TCIOS IB IVR CMRR	ERISTICS (Each Am i, unless otherwise not CONDITIONS $R_S \le 10k\Omega$ $R_S \le 10k\Omega$ $V_{CM} = \pm 12V, R_S \le 10k\Omega$ $V_S = \pm 5 \text{ to } \pm 15V,$	ed. COMIN	DP-09E DP-11E TYP 0.4 2.0 14 0.1 200 ± 13	MAX 0.8 10 30 0.3 350	#100	177-09F 177P 0.8 4.0 40 0.3 400 ±13	3.0 15 60 0.6 550	- COMIN	DP-110 TVP 1.5/ 4.0 250 0.3 400 ±13	MAX 6.0 — 300 0.6 800 —	UNITS mV nA/°C nA nA/°C nA V dB
ELECTRICAL Chor OP-09F, OP11F PARAMETER Input Offset Voltage Average Input Offset Voltage Drift Input Offset Current Average Input Offset Current Drift (Note 3) Input Bias Current Input Voltage Range Common-Mode Rejection Ratio Power Supply Rejection Ratio Large-Signal Voltage Gain	SYMBOL Vos TCVos Ios TCIos IB IVR CMRR	ERISTICS (Each Amai, unless otherwise not to unless that the unless otherwise to unless otherwise to unless otherwise not the unless ot	ed. MIN ±12 100	DP-09E DP-11E TYP 0.4 2.0 14 0.1 200 ±13 120	MAX 0.8 10 30 0.3 350 —	#12 100	17-09F 17-11F 17-0.8 4.0 40 0.3 400 ±13 120	3.0 15 60 0.6 550 —		DP-110 1/P 1.5/ 4.0 250 0.3 400 ±13 100	MAX 6.0 — 300 0.6 800 —	UNITS mV nA nA/°C nA V dB

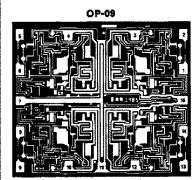
NOTES

^{1.} Total dissipation for all four amplifiers in package.

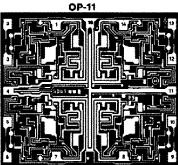
^{2.} Sample tested.

^{3.} Guaranteed but not tested.

DICE CHARACTERISTICS (125°C TESTED DICE AVAILABLE)



- 1. INVERTING INPUT (A)
 2. NONINVERTING INPUT (A)
 3. OUTPUT (A)
- 4. OUTPUT (B)
 5. NONINVERTING INPUT (B)
 6. INVERTING INPUT (B)
- 8. INVERTING INPUT (C)
 9. NONINVERTING INPUT (C)
 10. OUTPUT (C)
- 11. V+ 12. OUTPUT (D)
- 13. NONINVERTING INPUT (D)
 14. INVERTING INPUT (D)
- 15. V+



2: INVERTING INPUT (A)
3. NONINVERTING INPUT (A)
4. Y+
5. NONINVERTING INPUT (B)
6. INVERTING INPUT (B)
7. OUTPUT (B)
8. OUTPUT (C)
9. INVERTING INPUT (C)

16. NONINVERTING IMPUT (C)
11. V12. NONINVERTING IMPUT (D)
13. INVERTING IMPUT (D)

14. OUTPUT (D)

i. OUTPUT (A)

DIE SIZE 0.086 × 0.072 inch, 6192 sq. mils (2.18 × 1.83 mm, 3.99 sq. mm)

DIE SIZE 0.086 × 0.072 inch, 6192 sq. mils (2.18 × 1.83 mm, 3.99 sq. mm)

NOTE:

Either or both/V+ gads may be used without any change in performance.

WAPER TEST LIMITS at $V_S = \pm 15V$, $T_A = 25$ °C for SP-09/11N,/OR-09/11G and OP-09/11GR devices; $T_A = 125$ °C for OP-09/11N and OP-09/11gT devices, unless otherwise noted.

PARAMETER	SYMBOL	CONDITIONS	OP-09NT OP-11NT	OP-09N OP/11N	OP-09G/T OP-11GT	OP-11G	OP-09GR OP-11GR	_ UNITS
Input Offset Voltage	Vos	R _S ≤10kΩ	1.0	0.5	3.5/	2.5	5.0	mV MAX
Input Offset Current	los		20	20	7 / 50	50	200	A MAX
Input Bias Current	l _B		300	300	500	500	T 500/	nA MAX
Input Voltage Range	IVR		±12	±12	± 12	✓ ±12 [/ ±1/2	\ \v MIM\
Common-Mode Rejection Ratio	CMRR	V _{CM} = ± 12V R _S ≤ 10kΩ	100	100	100	100	40_	dB MIN
Power Supply Rejection Ratio	PSRR	$V_S = \pm 5V$ to $\pm 15V$ $R_S \le 10k\Omega$	32	32	32	32	100	μV/V MAX
Output Voltage Swing	V _O	$R_L \ge 10k\Omega$ $R_1 = 2k\Omega$	±11 ±11	± 12 ± 11	±11 ±11	±12 ±11	±11 ±11	V MIN
Large-Signal Voltage Gain	A _{VO}	$R_{L} \ge 2k\Omega$ $V_{O} = \pm 10V$	50	100	50	100	50	WmV MiN
Power Consumption (Four Amplifiers)	P _d	V _{OUT} = 0 No Load	200	180	200	180	340	mW MAX

NOTES:

For 25°C characteristics of NT & GT devices, see N & G characteristics, respectively.

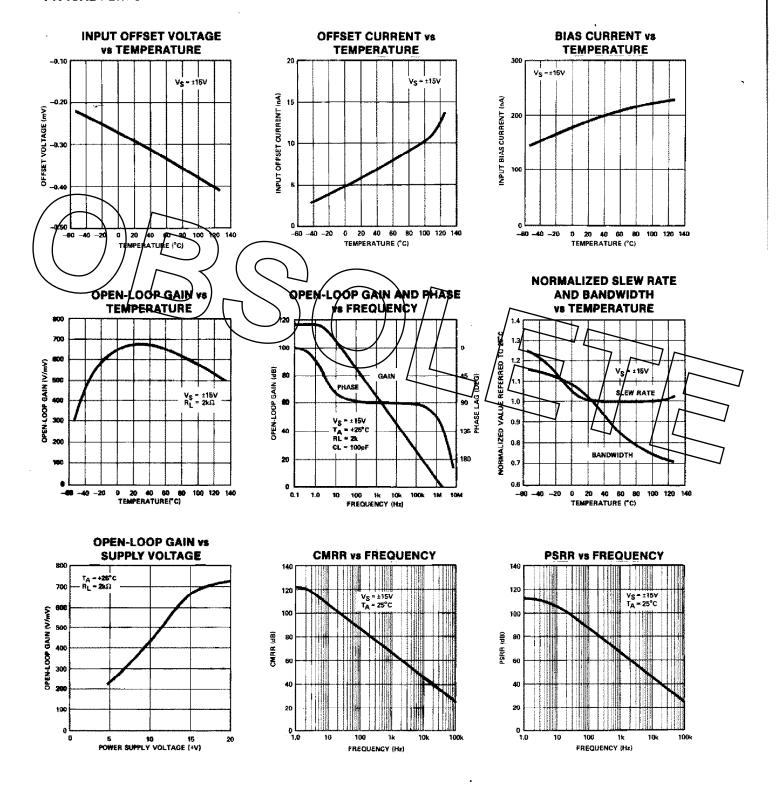
Electrical tests are performed at wafer probe to the limits shown. Due to variations in assembly methods and normal yield loss, yield after packaging is not guaranteed for standard product dice. Consult factory to negotiate specifications based on dice lot qualification through sample lot assembly and testing.

TYPICAL ELECTRICAL CHARACTERISTICS at V_S = ±15V, T_A = +25°C, unless otherwise noted.

PARAMETER	SYMBOL	CONDITIONS	OP-09NT OP-11NT TYPICAL	OP-09N OP-11N TYPICAL	OP-09GT OP-11GT TYPICAL	OP-11G TYPICAL	OP-09GR OP-11GR TYPICAL	UNITS
Slew Rate	SR	A _V = 1 R _L ≥ 2kΩ	*	1	1	1	1	V/μs
Unity Gain Bandwidth	GBW		2	2	2	2	2	MHz
Channel Separation	CS	A _V = 100 f = 10kHz R _S = 1kΩ	130	130	130	130	130	₫B

OP-09/0P-11

TYPICAL PERFORMANCE CHARACTERISTICS



TYPICAL PERFORMANCE CHARACTERISTICS

